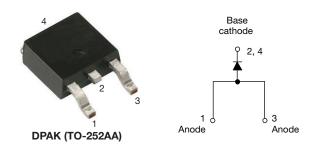
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Surface Mount Fast Soft Recovery Rectifier Diode, 8 A



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PRIMARY CHARACTERISTICS					
I _{F(AV)}	8 A				
V _R	1200 V				
V _F at I _F	1.3 V				
I _{FSM}	150 A				
t _{rr}	80 ns				
T _J max.	150 °C				
Package	DPAK (TO-252AA)				
Circuit configuration	Single				
Snap factor	0.6				

FEATURES

- Glass passivated pellet chip junction
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Meets JESD 201 class 2 whisker test
- Flexible solution for reliable AC power rectification
- High surge, low V_F rugged blocking diode for DC charging stations
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- On-board and off-board EV / HEV battery chargers
- Renewable energy inverters

DESCRIPTION

The VS-8EWF12SLHM3 fast soft recovery rectifier series has been optimized for combined short reverse recovery time, low forward voltage drop and low leakage current.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	Sinusoidal waveform	8	А		
V _{RRM}		1200	V		
I _{FSM}		150	A		
V _F	8 A, T _J = 25 °C	1.3	V		
t _{rr}	1 A, 100 A/µs	80	ns		
TJ	Range	-40 to +150	°C		

VOLTAGE RATINGS							
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA				
VS-8EWF12SLHM3	1200	1300	4				

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum average forward current	I _{F(AV)}	T_{C} = 96 °C, 180° conduction half sine wave	8			
Maximum peak one cycle		10 ms sine pulse, rated V _{RRM} applied	125	А		
non-repetitive surge current	IFSM	10 ms sine pulse, no voltage reapplied	150			
Maximum I ² t for fusing	l ² t	10 ms sine pulse, rated V _{RRM} applied	78	A ² s		
		10 ms sine pulse, no voltage reapplied	110	A-5		
Maximum I²√t for fusing	l²√t	t = 0.1 ms to 10 ms, no voltage reapplied	1100	A²√s		

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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS		UNITS	
Maximum forward voltage drop	V _{FM}	8 A, T _J = 25 °C		1.3	V	
Forward slope resistance	r _t	T.I = 150 °C		25.6	mΩ	
Threshold voltage	V _{F(TO)}	1j = 150°C		0.93	V	
Maximum reverse leakage current		T _J = 25 °C	$V_{B} = Rated V_{BBM}$	0.1	mA	
Maximum reverse leakage current	IRM	T _J = 150 °C	VR - naieu VRRM	4	ША	

RECOVERY CHARACTERISTICS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	· •		
Reverse recovery time	t _{rr}	In at 8 Ann	270	ns	I _{FM}		
Reverse recovery current	l _{rr}	I _F at 8 A _{pk} 25 A/μs	4.2	А			
Reverse recovery charge	Q _{rr}	T _J = 25 °C	1	μC			
Snap factor	S		0.6				

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range	T _J , T _{Stg}		-40 to +150	°C	
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	2.5	°C/W	
Typical thermal resistance, junction to ambient (PCB mount)	R _{thJA} ⁽¹⁾		50	C/W	
Approximate weight			1	g	
Approximate weight			0.03	oz.	
Marking device		Case style DPAK (TO-252AA)	8EWF	12SH	

Note

 $^{(1)}$ When mounted on 1" square (650 mm²) PCB of FR-4 or G-10 material 4 oz. (140 μm) copper 40 °C/W

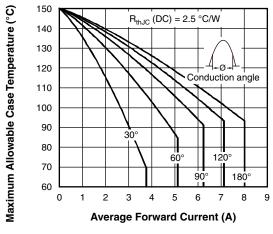


Fig. 1 - Current Rating Characteristics

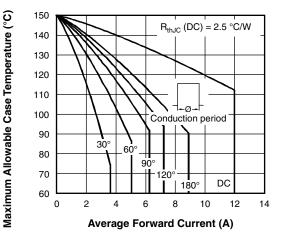


Fig. 2 - Current Rating Characteristics

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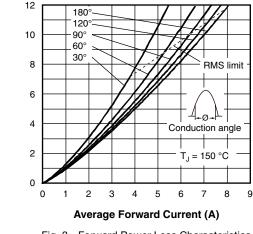
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Maximum Average Forward Power Loss (W)

Maximum Average Forward Power Loss (W)

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Fig. 3 - Forward Power Loss Characteristics

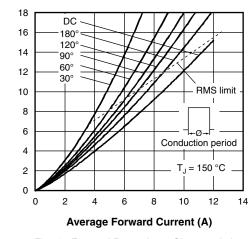


Fig. 4 - Forward Power Loss Characteristics

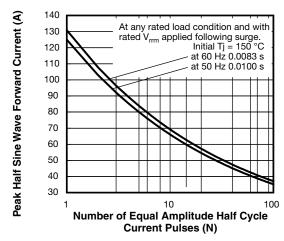


Fig. 5 - Maximum Non-Repetitive Surge Current

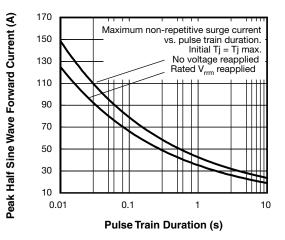


Fig. 6 - Maximum Non-Repetitive Surge Current

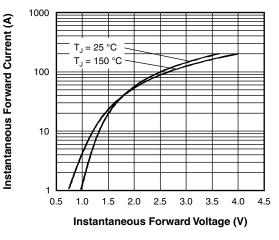


Fig. 7 - Forward Voltage Drop Characteristics

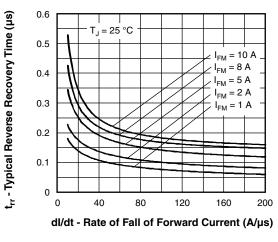
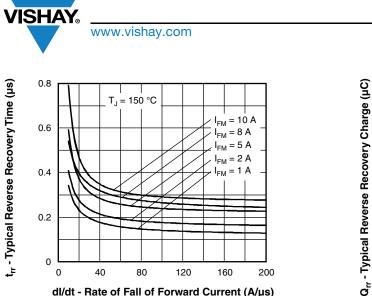


Fig. 8 - Recovery Time Characteristics, T_J = 25 °C

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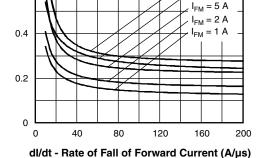


Fig. 9 - Recovery Time Characteristics, T_J = 150 °C

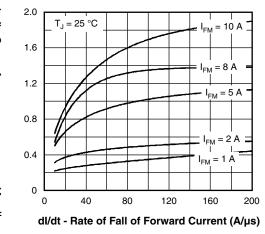


Fig. 10 - Recovery Charge Characteristics, T_J = 25 °C

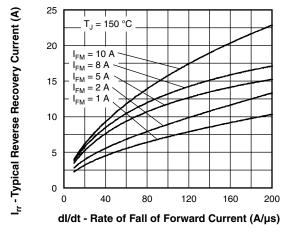


Fig. 13 - Recovery Current Characteristics, T_J = 150 °C



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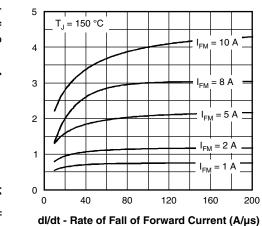


Fig. 11 - Recovery Charge Characteristics, T_J = 150 °C

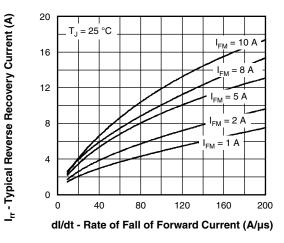


Fig. 12 - Recovery Current Characteristics, $T_J = 25$ °C

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VS-8EWF12SLHM3

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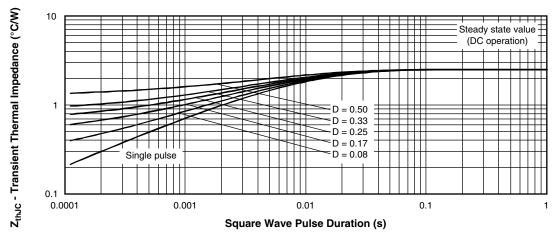


Fig. 14 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE

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SHA

Device code	vs-	8	Е	w	F	12	S	L	н	М3
		2	3	4	5	6	7	8	9	10
	1	- Vis	hay Sen	nicondu	ctors pro	oduct				
	2	- Cur	rent rati	ng (8 =	8 A)					
	3	- Circ	cuit conf	iguratio	n:					
	4	- Pao	single kage: DPAK	(TO-25)	244)					
	5	- Тур	e of silio fast sof	con:		ier				
	6		tage coo		-	_	12 = 12	00 V		
	7	- S=	surface	mounta	able	L				
	8	• L=	tape an	d reel (l	eft orier	ted), fo	r differe	nt orien	tation co	ontact fa
	9	. н=	AEC-Q	101 qua	alified					
	10		rironmer	•						
		M3	= halog	en-free,	RoHS-0	complia	nt, and	termina	tions lea	ad (Pb)-1

ORDERING INFORMATION (Example)							
PREFERRED P/N QUANTITY PER T/R MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION							
VS-8EWF12SLHM3	3000	3000	13" diameter reel				

LINKS TO RELATED DOCUMENTS					
Dimensions www.vishay.com/doc?95519					
Part marking information	www.vishay.com/doc?95518				
Packaging information	www.vishay.com/doc?96495				
SPICE model	www.vishay.com/doc?97057				

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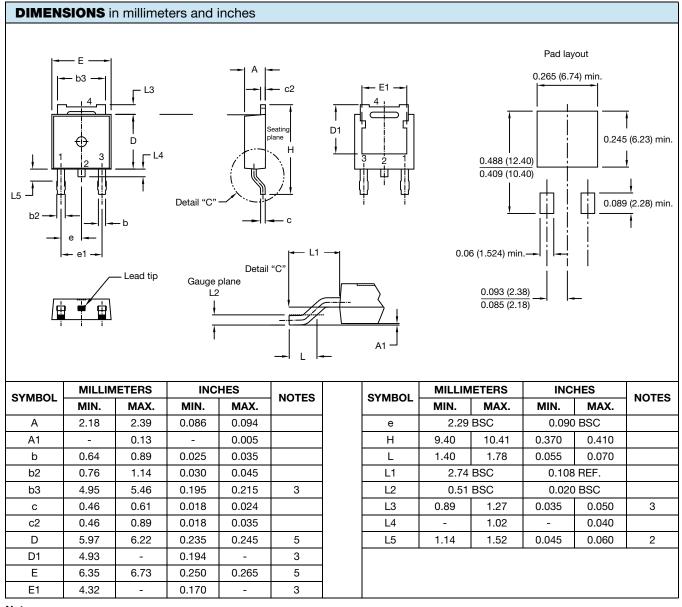
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Outline Dimensions



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DPAK (TO-252AA)



Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Lead dimension uncontrolled in L5

⁽³⁾ Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad

(4) Dimensions D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

⁽⁵⁾ Outline conforms to JEDEC[®] outline TO-252AA, except for D1 dimension



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